

FORM PTO-1449		SERIAL NO. 10/561,299	CASE NO. 9905/34 (BIF023273US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT		FILING DATE December 15, 2005	GROUP ART UNIT 2891
(use several sheets if necessary)	APPLICANT(S): Jean-Pierre Joly et al.		CONFIRMATION NO. 3881

REFERENCE DESIGNATION
U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER <small>Number-Kind Code (if known)</small>	DATE	NAME	CLASS/ SUBCLASS	FILING DATE
	D1	3,901,423	08/1975	Hillberry, et al.		
	D2	3,915,757	10/1975	Engel		
	D3	3,957,107	05/1976	Altoz et al.		
	D4	3,993,909	11/1976	Drews et al.		
	D5	4,006,340	02/1977	Gorinas		
	D6	4,028,149	06/1977	Deines et al.		
	D7	4,039,416	08/1977	White		
	D8	4,074,139	02/1978	Pankove		
	D9	4,107,350	08/1978	Berg et al.		
	D10	4,108,751	08/1978	King		
	D11	4,170,662	10/1979	Weiss et al.		
	D12	4,244,348	01/1981	Wilkes		
	D13	4,252,837	02/1981	Auton		
	D14	4,254,590	03/1981	Eisele et al.		
	D15	4,274,004	06/1981	Kanai		
	D16	4,324,631	08/1982	White et al.		
	D17	4,346,123	08/1982	Kaufmann		
	D18	4,361,600	11/1982	Brown		
	D19	4,368,083	01/1983	Bruel et al.		
	D20	4,412,868	11/1983	Brown et al.		
	D21	4,452,644	06/1984	Bruel et al.		
	D22	4,468,309	08/1984	White		
	D23	4,471,003	09/1984	Cann		
	D24	4,486,247	12/1984	Ecer et al.		
	D25	4,490,190	12/1984	Speri		
	D26	4,500,563	02/1985	Ellenberger et al.		
	D27	4,508,056	04/1985	Bruel et al.		
	D28	4,536,657	08/1985	Bruel		
	D29	4,539,050	09/1985	Kramler et al.		
	D30	4,542,863	09/1985	Larson		
	D31	4,566,403	01/1986	Fournier		
	D32	4,567,505	01/1986	Pease		
	D33	4,568,563	02/1986	Jackson et al.		
	D34	4,585,945	04/1986	Bruel et al.		
	D35	4,630,093	12/1986	Yamaguchi et al.		
	D36	4,684,535	08/1987	Heinecke et al.		
	D37	4,704,302	11/1987	Bruel et al.		

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	D38	4,717,683	01/1988	Parrillo et al.		
	D39	4,764,394	08/1988	Conrad		
	D40	4,832,253	05/1989	Kloucek et al.		
	D41	4,837,172	06/1989	Mizuno et al.		
	D42	4,846,928	07/1989	Dolins et al.		
	D43	4,847,792	07/1989	Barna et al.		
	D44	4,853,250	08/1989	Boulos et al.		
	D45	4,887,005	12/1989	Rough et al.		
	D46	4,891,329	01/1990	Reisman et al.		
	D47	4,894,709	01/1990	Phillips et al.		
	D48	4,904,610	02/1990	Shyr		
	D49	4,920,396	04/1990	Shinohara et al.		
	D50	4,929,566	05/1990	Beitman		
	D51	4,931,405	06/1990	Kamijo et al.		
	D52	4,948,458	08/1990	Ogle		
	D53	4,952,273	08/1990	Popov		
	D54	4,956,698	09/1990	Wang		
	D55	4,960,073	10/1990	Suzuki et al.		
	D56	4,975,126	12/1990	Margail et al.		
	D57	4,982,090	01/1991	Wittmaack		
	D58	4,996,077	02/1991	Moslehi et al.		
	D59	5,015,353	05/1991	Hubler et al.		
	D60	5,036,023	07/1991	Dautremont-Smith et al.		
	D61	5,110,748	05/1992	Sarma		
	D62	5,120,666	06/1992	Gotou		
	D63	5,131,968	07/1992	Wells et al.		
	D64	5,138,422	08/1992	Fujii et al.		
	D65	5,198,371	03/1993	Li		
	D66	5,200,805	04/1993	Parsons et al.		
	D67	5,242,863	09/1993	Xiang-Zheng et al.		
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	D70	5,280,819	01/1994	Newkirk et al.		
	D71	5,300,788	04/1994	Fan et al.		
	D72	5,374,564	12/1994	Bruel		
	D73	5,400,458	03/1995	Rambosek		
	D74	5,442,205	08/1995	Brasen et al.		
	D75	5,494,835	02/1996	Bruel		
	D76	5,524,339	06/1996	Gorowitz et al.		
	D77	5,559,043	09/1996	Bruel		
	D78	5,611,316	03/1997	Oshima et al.		
	D79	5,622,896	04/1997	Knotter et al.		
	D80	5,633,174	05/1997	Li		

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	D81	5,714,395	02/1998	Bruel		
	D82	5,753,038	05/1998	Vichr et al.		
	D83	5,804,086	09/1998	Bruel		
	D84	5,863,830	01/1999	Bruel et al.		
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	D86	5,882,987	03/1999	Srikrishnan		
	D87	5,897,331	04/1999	Sopori		
	D88	5,909,627	06/1999	Egloff		
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	D90	5,993,677	11/1999	Biasse et al.		
	D91	6,013,954	01/2000	Hamajima		
	D92	6,054,370	04/2000	Doyle		
	D93	6,071,795	06/2000	Cheung et al.		
	D94	6,127,199	10/2000	Inoue		
	D95	6,146,979	11/2000	Henley et al.		
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	D102	6,316,333 B1	11/2001	Bruel et al.		
	D103	6,323,108 B1	11/2001	Kub et al.		
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	D106	6,362,082 B1	03/2002	Doyle et al.		
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	D115	7,067,396 B2	06/2006	Aspar et al.		
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	D117	7,498,234 B2	03/2009	Aspar et al.		
	D118	7,615,463 B2	11/2009	Aspar et al.		
	D119	7,670,930 B2	03/2010	Tauzin et al.		
	D120	7,713,369 B2	05/2010	Aspar et al.		
	D121	7,772,087 B2	08/2010	Nguyen et al.		
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	D123	7,902,038 B2	03/2011	Aspar et al.		

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	D124	RE39,484 E	02/2007	Bruehl		
	D125	2001/0007367 A1	07/2001	Ohkubo		
	D126	2002/0025604 A1	02/2002	Tiwari		
	D127	2002/0048948 A1	04/2002	Gang		
	D128	2002/0081861 A1	06/2002	Robinson et al.		
	D129	2002/0145489 A1	10/2002	Cornett et al.		
	D130	2002/0153563 A1	10/2002	Ogura		
	D131	2002/0083387 A1	06/2002	Miner et al.		
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	D138	2009/0130392 A1	05/2009	Aspar et al.		
	D139	2009/0156016 A1	06/2009	Di Cioccio		
	D140	2010/0025228 A1	02/2010	Tauzin et al.		
	D141	2010/0167499 A1	07/2010	Fournel et al.		
	D142	2010/0216294 A1	08/2010	Rabarot et al.		
	D143	2010/0323497 A1	12/2010	Fournel		

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EXAMINER INITIAL		DOCUMENT NUMBER <small>Number-Kind Code (if known)</small>	DATE	COUNTRY	CLASS/ SUBCLASS	TRANSLATION YES OR NO
	D144	EP 0 293 049 B1	09/1993	EPO		
	D145	EP 0 355 913 A1	02/1990	EPO		
	D146	EP 0 383 391 A1	08/1990	EPO		
	D147	EP 0 533 551 A1	03/1993	EPO		ABSTRACT
	D148	EP 0 660 140 A1	06/1995	EPO		ABSTRACT
	D149	EP 0 665 588 A1	08/1995	EPO		ABSTRACT
	D150	EP 0 703 609 A1	03/1996	EPO		ABSTRACT
	D151	EP 0 754 953 B1	01/1997	EPO		ABSTRACT
	D152	EP 0 786 801 A1	07/1997	EPO		ABSTRACT
	D153	EP 0 801 419 A1	10/1997	EPO		ABSTRACT
	D154	EP 0 895 282 A2	02/1999	EPO		
	D155	EP 0 898 307 A1	02/1999	EPO		ABSTRACT
	D156	EP 0 902 843 B1	03/2000	EPO		ABSTRACT
	D157	EP 0 917 193 A1	05/1999	EPO		
	D158	EP 0 938 129 A1	08/1999	EPO		
	D159	EP 0 994 503 A1	04/2000	EPO		ABSTRACT
	D160	EP 1 059 663 A2	12/2000	EPO		
	D161	FR 2 771 852 A1	06/1999	FRANCE		ABSTRACT

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	D162	FR 2 789 518 A1	08/2000	FRANCE		ABSTRACT
	D163	JP 61-129872 A	06/1986	JAPAN		ABSTRACT
	D164	JP 01-128570 A	05/1989	JAPAN		ABSTRACT
	D165	JP 01-169917 A	07/1989	JAPAN		ABSTRACT
	D166	JP 11-233449 A	08/1999	JAPAN		ABSTRACT
	D167	WO 02/05344 A1	01/2002	WIPO		
	D168	WO 02/84721 A1	10/2002	WIPO		ABSTRACT
	D169	WO 02/84722 A1	10/2002	WIPO		ABSTRACT
	D170	WO 03/013815 A1	02/2003	WIPO		
	D171	WO 03/032384 A1	04/2003	WIPO		
	D172	WO 2004/044976 A1	05/2004	WIPO		
	D173	WO 2004/059711 A1	07/2004	WIPO		
	D174	WO 2004/064146 A1	07/2004	WIPO		ABSTRACT
	D175	WO 2005/019094 A1	03/2005	WIPO		ABSTRACT
	D176	WO 2005/043615 A1	05/2005	WIPO		ABSTRACT
	D177	WO 2007/020351 A1	02/2007	WIPO		ABSTRACT
	D178	WO 2007/036631 A1	04/2007	WIPO		ABSTRACT
	D179	WO 2007/110515 A2	10/2007	WIPO		ABSTRACT
	D180	WO 2008/093008 A2	08/2008	WIPO		ABSTRACT
	D181	WO 2009/087290 A1	07/2009	WIPO		ABSTRACT

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.	
	D182	Agarwal et al, "Efficient Production of Silicon-On-Insulator Films by Co-Implantation of HE ⁺ with H ⁺ ", <i>Applied Physics Letters</i> , Vol. 72, No. 9, 1998, pp 1086-1088.
	D183	Agarwal, Aditya et al. "Efficient Production of Silicon-On-Insulator Films by Co-Implantation of He ⁺ with H ⁺ " – Proceedings 1997 IEEE International SOI Conference, October 1997 – pp. 44-45.
	D184	Ahn, K. Y., et al., "Growth, Shrinkage, And Stability of Interfacial Oxide Layers Between Directly Bonded Silicon Wafers", <i>Applied Physics A.</i> , Vol. 50, 1990, pp 85-94.
	D185	Alley et al., "Surface Roughness Modification of Interfacial Contacts In Polysilicon Microstructures", Proceedings of the 7 th International Conference on Solid-State Sensors and Actuators, <i>Transducers '93</i> , PACIFICO, Yokohama JAPAN. Jun 7-10, 1993, pp 288-291.
	D186	Ascheron, C., "A Comparative Study of Swelling, Radiation, Strain and Radiation Damage of High-Energy Proton-bombarded GaAs, GaP, InP, Si and Ge Single Crystals, Nuclear Instruments and Methods in Physics Research", <i>Nuclear Instruments and Methods In Physics Research B36</i> , (1989), 163-172.
	D187	Ascheron, C., "A Study of Proton Bombardment Induced Swelling of GaP Single Crystals", <i>Phys. stat. sol. (a)</i> 92, (1985), pp 169-176.

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	D188	Ascheron, C., "Gettering a Copper in Proton-and Helium-Bombarded Buried Regions of Gallium Phosphide", <i>Phys. stat. sol. (a)</i> , Vol. 106, 1988, pp 73-79.
	D189	Ascheron, C., "Investigations of Hydrogen Implanted GaP Single Crystals by Means of Particle Induced 7-Spectroscopy, Infrared Spectroscopy, and Turyherford Backscattering Channeling Technique" <i>Phys. stat. sol. (a)</i> 89, (1985), pp 549-557.
	D190	Ascheron, C., "Proton Beam Modification of Selected AlIBV Compounds", <i>Phys. stat. sol. (a)</i> 124, (1991), pp 11.
	D191	Ascheron, C., "Swelling, Strain, and Radiation Damage of He+ Implanted GaP", <i>Phys. stat. sol. (a)</i> 96, 1986, pp. 555-562. (1986).
	D192	Asheron, C., "The Effect of Hydrogen Implantation Induced Stress on GaP Single Crystals", <i>Nuclear Instruments and Methods in Physics Research</i> , B28 (1987), pp 350-359.
	D193	Aspar et al., "The Generic Nature of the Smart-Cut® Process for Thin-Film Transfer", <i>Journal of Electronic Materials</i> , Vol. 30, No. 7, March - 2001, pp 834-840.
	D194	Aspar, B. "Basic Mechanisms Involved in the Smart-Cut Process", 1997, pp. 223-240.
	D195	Aspar, B. et al, "Characterization of SOI substrates: Application to Recent SIMOX and UNIBOND Wafers," <i>Electrochemical Society Proceedings</i> , vol. 96-3, pp. 99-111.
	D196	Aspar, B. et al, "Transfer of Structured and Patterned Thin Silicon Films Using the Smart-Cut Process", 1996, pp. 1985-1986.
	D197	Aspar, B. Et al., "Ultra Thin Buried Oxide Layers Formed By Low Dose SIMOX Processes", Proc. 6 th International Conference on SOI Technology and Devices, <i>Electro. Soc.</i> , Vol. 94, No. 11, 1994, pp 62.
	D198	Aspar, B. et al., "Smart Cut – Process Using Metallic Bonding: Application to Transfer of Si, GaAs, InP Thin Films", <i>Electronic Letters</i> – June 10, 1999, Vol. 35, No. 12., pp. 1024-1025.
	D199	Ashurst et al., "Water Level Anti-Stiction Coatings For MEMS", <i>Sensors and Actuators A104</i> , April 23, 2003, pp 213-221.
	D200	Auberton-Herve, A. J. et al, "A New Sal Material: Smart-Cut", 1996, pp.214-219.
	D201	Auberton-Herve, A.J. et al, "SOI Materials for ULSI Applications", <i>Semiconductor International</i> , Oct. 1995, 5 pps.
	D202	A. J. Auberton-Hervé, "Silicon-On-Insulator," <i>European Semiconductor</i> , Mar. 1997, pp. 17 and 18.
	D203	A. J. Auberton-Hervé, "Why Can Smart Cut® Change The Future Of Microelectronics?," Published in International Journal of High Speed Electronics and Systems, Vol. 10, No. 1 (2000) pgs. 131-146.
	D204	Blanchard-Lagahe C. et al., "Hydrogen and Helium Implantation to Achieve Layer Transfer" Vol. 19, pp. 346-358, April 2003, <i>Semiconductor Wafer Bonding VII: Science, Technology, and Applications – Proceedings of the International Symposium</i> .

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	D205	Blöchl P.E. et al., "First-Principles Calculations of Diffusion Coefficients: Hydrogen in Silicon, <i>Physical Review Letters</i> , Vol. 64, No. 12, 1990, pp 1401-1404.
	D206	Borgati, Stephen P., "The Root-Mean-Square", Boston College, Nov. 16, 1998, Obtained from the Internet at: < http://www.analytictech.com/mb313/rootmean.htm >.
	D207	Bruehl, M. et al., (Vol. 99-1) Meeting Abstract No. 333, "Single Crystal Semiconductor Layer Delamination and Transfer Through Hydrogen Implantation", The 195 th Meeting of the Electrochemical Society, May 2-6, 1999, Seattle, Washington.
	D208	Bruehl, Michel, "Application of Hydrogen Ion Beams To Silicon on Insulator Material Technology", <i>Nuclear Instruments and Methods in Physics Research</i> , B108, 1996, pp 313-319.
	D209	Bruehl, M. et al., "Smart-Cut: A New Silicon on Insulator Material Technology Based on Hydrogen Implantation and Wafer Bonding", 1997, pp. 1636-164, Col. 36, Part 1, No. 3B.
	D210	Bruehl, M. "Smart-Cut Process: The Way to Unibond S.O.I. Wafers", 1996, pages unknown.
	D211	Bruehl, M. et al, "Smart-Cut": A Promising New SOI material technology, <i>Proceedings 1994 IEEE, International Sol Conference</i> , Oct. 1995, pp. 178-179.
	D212	Bruehl, M. et al, "Smart-Cut-a new SOI Material Technology based on hydrogen Implantation and wafer bonding," <i>CEA</i> , 1996, 24 pages.
	D213	Bruehl, M., "Silicon on insulator Material Technology", <i>Electronic Letters</i> ; 31 (1995) Jul. 6; No. 14; pp. 1201-1202.
	D214	Bruehl, M., "Silicon-an-Insulator", <i>European Semiconductor</i> , Mar. 1997.
	D215	Camperi-Ginestet et al., "Alignable Epitaxial Liftoff of GaAs Materials With Selective Deposition Using Polyimide Diaphragms", <i>IEEE Transactions Photonics Technology Letters</i> , Vol. 3, No. 12, 1991, pp 1123-1126.
	D216	Canham et al. "Radiative Recombination Channels due to Hydrogen In Crystalline Silicon", <i>Materials Science and Engineering</i> , B4 (1989) pp. 41-45.
	D217	Carter et al., "Applications of Ion Beams to Materials", <i>Inst. Phys. Conf. Ser.</i> , No. 28, Chapter 1, 1976, pp 30-36.
	D218	Carter, G. et al., "The Collection of Ions Implanted In Semiconductors: II Range Distributions Derived From Collection and Sputter-Etch Curves, <i>Radiation Effects</i> , 1972, Vol. 16, pp 107-114.
	D219	Cassidy, Victor M., "Ion Implantation Process Toughens Metalworking Tools," <i>Modern Metals</i> , 1984, pp. 65-67.
	D220	Cerofolini et al., "Hydrogen-Related Complexes as the Stressing Species in High-Fluence, Hydrogen-Implanted, Single-Crystal Silicon" <i>Physical Review B</i> , vol. 46, No.4, 1992, pp. 2061-2070.
	D221	Cerofini et al., "Ultradense Gas Bubbles in Hydrogen-or-Helium-Implanted (or Co-Implanted) Silicon", <i>Materials Science and Engineering</i> , B71, 2000, pp 196-202.

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	D222	Cerofolini et al., "Hydrogen and Helium Bubbles In Silicon", <i>Material Science and Engineering 2000</i> – Reports: A Review Journal, Published By Elsevier Science S.A. 2000, pp. 1-52.
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	D244	Feng et al., "Generalized Formula For Curvature Radius and Layer Stresses Caused By Thermal Strain In Semiconductor Multilayer Structures", <i>J. Appl. Phys.</i> , Vol. 54, No. 1, 1983, pp 83-85.
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	D332	Weldon et al., "Mechanism Of Silicon Exfoliation Induced by Hydrogen/Helium Co-implantation", <i>Applied Physics Letters</i> , Vol. 73, No. 25, pp 3721-3723, Dec 21, 1998.
	D333	Wemple, S.H., "Optical and channeling studies of ion-bombarded GaP", <i>J. Appl. Phys.</i> , vol. 45, No.4, Apr. 1974, pp 1578-1588.
	D334	Whitton, J. L. et al., "The Collection of Ions Implanted In Semiconductors: 1 Saturations Effects", <i>Radiation Effects</i> , Scotland, Vol. 16, 1972, pp 101-105.
	D335	Williams J. et al., "Annealing behaviour of high-dose rare-gas implantations into silicon", from Application of Ion Beams to Materials, 1975, Chap. 1, <i>Inst. Phys. Conf. Ser. No. 28</i> , 1976, pp 30-36.
	D336	Wittmaack et al., "High Fluence Retention of Noble Gases Implanted in Silicon" <i>Radiation Effects</i> , vol. 39, 1978, pp. 81-95.
	D337	Wolf, Stanley Ph.D., <i>Silicon Processing for the VLSI Era</i> (vol. 2), Lattice Press, 1990, pp. 66-79.
	D338	Wong et al., "Integration of GaN Thin Films With Dissimilar Substrate Materials by Pd-In Metal Bonding and Laser Lift-Off", <i>Journal of Electronic Materials</i> , Vol. 28, No. 12, 1999, pp 1409-1413.
	D339	Yamaguchi H. et al., "Intelligent Power IC With Partial Soi Structure", <i>Jpn. J. Appl. Phys.</i> , Vol. 34, 1995, pp 864-868.
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	D340	Yee et al., "Polysilicon Surface-Modification Technique to Reduce Sticking of Microstructures", <i>Sensors and Actuators A</i> 52, 1996, pp. 145-150.
	D341	Yun et al., "Fractional Implantation Area Effects on Patterned Ion-Cut Silicon Layer Transfer", Dept. of Electrical Eng, and Computer Sciences, University of California, Berkley, CA, 94720, USA, 1999 IEEE International SOI Conference, Oct, 1999, pp 129-30.
	D342	Yun et al., "Thermal and Mechanical Separations of Silicon Layers From Hydrogen Pattern-Implanted Wafers", <i>Journal of Electronic Materials</i> , Vol. 36, No. 8, April 24, 2001, pp 960-964.
	D343	Yun, H. et al., "Transfer of Patterned Ion-Cut Silicon Layers", <i>Applied Physics Letters</i> , Vol. 73, No. 19, 1998, pp 2772-2774.
	D344	International Search Report for International Application No. PCT/FR1998/002904, dated April 16, 1999, 2 pages.
	D345	International Search Report for International Application No. PCT/FR2002/001266, dated February 7, 2003, 4 pages.
	D346	International Search Report for International Application No. PCT/FR2002/001268, dated February 6, 2003, 4 pages.
	D347	International Search Report for International Application No. PCT/FR2002/003422, dated January 22, 2003, 3 pages.
	D348	International Search Report for International Application No. PCT/FR2003/003256, dated March 19, 2004, 6 pages.
	D349	International Search Report for International Application No. PCT/FR2003/003867, dated May 28, 2004, 3 pages.
	D350	International Search Report for International Application No. PCT/FR2003/003622, dated June 3, 2004, 3 pages.
	D351	International Search Report for International Application No. PCT/FR2004/001858, dated December 28, 2004, 3 pages.
	D352	International Search Report for International Application No. PCT/FR2004/002779, dated April 5, 2005, 3 pages.
	D353	International Search Report for International Application No. PCT/FR2004/002781, dated April 5, 2005, 3 pages.
	D354	International Search Report for International Application No. PCT/FR2004/001565, dated July 6, 2005, 3 pages.
	D355	International Search Report for International Application No. PCT/FR2006/001945, dated January 8, 2007, 3 pages.
	D356	International Search Report for International Application No. PCT/FR2006/002184, dated January 24, 2007, 2 pages.
	D357	International Search Report for International Application No. PCT/FR2007/000534, dated November 22, 2007, 3 pages.

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	D358	International Search Report for International Application No. PCT/FR2007/002100, dated February 4, 2009, 3 pages.
	D359	International Search Report for International Application No. PCT/FR2008/001427, dated July 1, 2009, 3 pages.
	D360	Office Action from US Application No. 12/063,808, dated April 6, 2010, 9 pages.
	D361	Office Action from US Application No. 12/063,808, dated September 22, 2010, 9 pages.
	D362	Office Action from US Application No. 10/534,199, dated February 19, 2009, 8 pages.
	D363	Office Action from US Application No. 10/534,199, dated August 5, 2009, 10 pages.
	D364	Office Action from US Application No. 10/534,199, dated January 20, 2010, 8 pages.
	D365	Office Action from US Application No. 10/534,199, dated August 4, 2010, 8 pages.
	D366	Office Action from US Application No. 10/577,175, dated June 22, 2009, 13 pages.
	D367	Office Action from US Application No. 10/577,175, dated April 13, 2010, 14 pages.
	D368	Office Action from US Application No. 11/480,250, dated May 22, 2008, 10 pages.
	D369	Office Action from US Application No. 11/480,250, dated December 3, 2008, 16 pages.
	D370	Office Action from US Application No. 11/480,250, dated January 26, 2010, 14 pages.
	D371	Office Action from US Application No. 11/480,250, dated August 3, 2010, 15 pages.
	D372	Office Action from US Application No. 12/088,047, dated September 25, 2009, 9 pages.
	D373	Office Action from US Application No. 12/088,047, dated March 10, 2010, 9 pages.
	D374	Office Action from US Application No. 10/565,621, dated January 7, 2010, 8 pages.
	D375	Office Action from US Application No. 10/565,621, dated November 23, 2010, 11 pages.
	D376	Office Action from US Application No. 12/628,772, dated October 7, 2010, 12 pages.
	D377	Notice of Allowance from US Application No. 12/336,229, dated September 29, 2010, 7 pages.
	D378	Notice of Allowance from US Application No. 12/336,229, dated January 10, 2011, 4 pages.
	D379	Office Action from US Application No. 12/682,522, dated March 29, 2011, 10 pages.
	D380	Notice of Allowance from US Application No. 10/468,223, dated December 28, 2009, 4 pages.
	D381	Office Action from US Application No. 10/474,984, dated March 11, 2010, 13 pages.
	D382	Notice of Allowance from US Application No. 10/474,984, dated October 28, 2010, 6 pages.
	D383	Office Action from US Application No. 10/540,303, dated December 18, 2007, 6 pages.
	D384	Notice of Allowance from US Application No. 10/540,303, dated October 7, 2008, 9 pages.

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	D385 Office Action from US Application No. 11/327,906, dated October 1, 2007, 5 pages.
	D386 Office Action from US Application No. 11/327,906, dated February 11, 2008, 5 pages.
	D387 Notice of Allowance from US Application No. 11/327,906, dated September 15, 2008, 6 pages.
	D388 Office Action from US Application No. 10/975,826, dated May 5, 2006, 14 pages.
	D389 Office Action from US Application No. 10/975,826, dated November 28, 2006, 20 pages.
	D390 Office Action from US Application No. 10/975,826, dated July 17, 2007, 21 pages.
	D391 Office Action from US Application No. 10/975,826, dated April 1, 2008, 27 pages.
	D392 Office Action from US Application No. 10/975,826, dated December 10, 2008, 28 pages.
	D393 Office Action from US Application No. 10/975,826, dated September 2, 2009, 24 pages.
	D394 Notice of Allowance from US Application No. 10/975,826, dated April 28, 2010, 8 pages.
	D395 Office Action from US Application No. 10/492,343, dated October 17, 2005, 6 pages.
	D396 Office Action from US Application No. 10/492,343, dated June 6, 2006, 13 pages.
	D397 Office Action from US Application No. 10/492,343, dated November 14, 2006, 13 pages.
	D398 Office Action from US Application No. 10/492,343, dated May 29, 2007, 15 pages.
	D399 Office Action from US Application No. 10/492,343, dated February 7, 2008, 18 pages.
	D400 Office Action from US Application No. 10/492,343, dated August 18, 2008, 12 pages.
	D401 Office Action from US Application No. 10/492,343, dated December 22, 2008, 9 pages.
	D402 Notice of Allowance from US Application No. 10/492,343, dated June 26, 2009, 6 pages.
	D403 Office Action from US Application No. 11/747,733, dated March 16, 2009, 9 pages.
	D404 Office Action from US Application No. 11/747,733, dated March 23, 2010, 5 pages.
	D405 Notice of Allowance from US Application No. 11/747,733, dated September 29, 2010, 8 pages.
	D406 Notice of Allowance from US Application No. 12/293,193, dated October 8, 2009, 10 pages.
	D407 Expert Report of Marcus Weldon, Ph.D. dated November 1, 2000
	D408 Expert Report of Jean-Pierre Colinge dated November 1, 2000.
	D409 Expert Report of Chris Van de Walle, Ph.D. dated November 1, 2000
	D410 Memorandum in Support of Defendant Silicon Genesis Corporation's Motion for Summary Judgment of Invalidity for Lack of Enablement dated March 19, 2001
	D411 Memorandum of Points and Authorities In Support of Soitec's Motion for Summary Judgment on Sigen's Enablement Invalidity Claim (Redacted) dated March 27, 2001
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	D412	Soitec's Memorandum of Points and Authorities In Opposition to Silicon Genesis Corporation's Motion for Summary Judgment of Invalidity for Lack of Enablement dated April 11, 2001
	D413	Memorandum in Support of Defendant Silicon Genesis Corporation's Opposition to Soitec's Motion for Summary Judgment on SiGen's Defense of Enablement dated April 20, 2001
	D414	Reply Memorandum in Support of Defendant Silicon Genesis Corporation's Motion for Summary Judgment of Invalidity for Lack of Enablement dated April 30, 2001
	D415	Expert Report of Marcus Weldon, Ph.D. dated August 24, 2001
	D416	Report of Jean-Pierre Colinge in Response to SiGen Enablement and Indefiniteness Expert Reports of August 24, 2001
	D417	Expert Report of Chris Van de Walle, Ph.D. dated August 24, 2001
	D418	Memorandum and Order re: Summary Judgment [denied] dated February 5, 2002
	D419	Plaintiff's Memorandum in Support of Their Motion for Judgment As a Matter of Law and a New Trial dated May 10, 2002
	D420	Silicon Genesis Corporation's Opposition to Plaintiff's Motion for Judgment as a Matter of Law and a New Trial dated June 17, 2002
	D421	Memorandum of Law in Support of Plaintiff's Motion for Judgment on SiGen's Indefiniteness Defense dated June 20, 2002
	D422	Plaintiff's Reply Memorandum in Support of Their Motion for Judgment as a Matter of Law and a New Trial dated July 18, 2002
	D423	Defendant Silicon Genesis Corporation's Opposition to Soitec's Motion for Judgment Re Indefiniteness and Cross-Motion for Judgment of Indefiniteness dated July 19, 2002
	D424	Plaintiff's Reply in Support of their Motion for Judgment on SiGen's Indefiniteness Defense dated July 25, 2002
	D425	Memorandum and Order re: Post-Trial Motions dated August 23, 2002
	D426	Judgment dated October 21, 2002.
	D427	Brief of Plaintiffs-Appellants Soitec, S.A. and Commissariat a L'Energie Atomique dated January 28, 2003
	D428	Brief for Defendant-Cross Appellant Silicon Genesis Corporation dated March 22, 2003
	D429	Reply Brief of Plaintiffs-Appellants Soitec, S.A. and Commissariat a L'Energie Atomique dated May 5, 2003
	D430	Reply Brief for Defendant-Cross Appellant Silicon Genesis Corporation dated May 19, 2003
	D431	Plaintiff/Appellants Supplemental Authority Letter [dated November 17, 2003].
	D432	Defendant-Cross Appellant's Response To Appellants' Submission Of <i>CFMT, Inc. v. Yieldup Int'l</i> , [dated November 24, 2003].

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	D433	Decision from the United States Court of Appeals for the Federal Circuit dated November 26, 2003.
	D434	Combined Petition for Panel Rehearing and for Rehearing En Banc by Plaintiffs-Appellant's Soitec, S.A. and Commissariat A L'Energie Atomique, dated December 10, 2003.
	D435	Order [dated January 7, 2004 denying Appellants' petition for panel rehearing and Appellant's petition for rehearing en banc].
	D436	Judgment Mandate [dated January 14, 2004].
	D437	MOTION to Bifurcate the Issues of Willfulness and Damages for Purposes of Discovery and Trial and proposed Form of Order - filed by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 10/20/2009). CORRECTING ENTRY: Docket clerk deleted D.I. 78 (opening brief) due to document being filed improperly. Counsel is advised to re-file document using the OPENING BRIEF event code rather than the combined opening and answering brief event code. (lid) (Entered: 10/21/2009)
	D438	OPENING BRIEF in Support re <u>77</u> MOTION to Bifurcate the Issues of Willfulness and Damages for Purposes of Discovery and Trial and proposed Form of Order filed by MEMC Electronic Materials Inc.. Answering Brief/Response due date per Local Rules is 11/9/2009. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Exhibit B, # <u>3</u> Exhibit C)(Rogowski, Patricia) (Entered: 10/21/2009)
	D439	Cross MOTION to Bifurcate all Collateral Issues - filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a LEnergie Atomique. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 11/09/2009)
	D440	ANSWERING BRIEF in Opposition re <u>85</u> Cross MOTION to Bifurcate all Collateral Issues, <u>77</u> MOTION to Bifurcate the Issues of Willfulness and Damages for Purposes of Discovery and Trial and proposed Form of Order filed by SOITEC Silicon On Insulator Technologies SA, Commissariat a LEnergie Atomique. Reply Brief due date per Local Rules is 11/20/2009. (Attachments: # <u>1</u> Exhibit, # <u>2</u> Exhibit, # <u>3</u> Exhibit, # <u>4</u> Exhibit, # <u>5</u> Exhibit, # <u>6</u> Exhibit, # <u>7</u> Exhibit, # <u>8</u> Exhibit, # <u>9</u> Exhibit, # <u>10</u> Exhibit, # <u>11</u> Exhibit, # <u>12</u> Declaration, # <u>13</u> Certificate of Service)(Kraft, Denise) (Entered: 11/09/2009)
	D441	REPLY BRIEF re <u>77</u> MOTION to Bifurcate the Issues of Willfulness and Damages for Purposes of Discovery and Trial and proposed Form of Order filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Exhibit 1, # <u>2</u> Exhibit 2, # <u>3</u> Exhibit 3)(Rogowski, Patricia) (Entered: 11/17/2009)

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	D442	ANSWERING BRIEF in Opposition re <u>85</u> Cross MOTION to Bifurcate all Collateral Issues filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 12/3/2009. (Rogowski, Patricia) (Entered: 11/19/2009)
	D443	REPLY BRIEF re <u>85</u> Cross MOTION to Bifurcate all Collateral Issues filed by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Exhibit Declaration of Marcus T. Hall in Support of Plaintiffs' Reply Re: Cross-Motion to Bifurcate all Collateral Issues)(Kraft, Denise) (Entered: 12/03/2009)
	D444	NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Production of Three Boxes of Wafer Samples by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 12/08/2009). Set Hearings: Discovery Conference set for 12/21/2009 04:00 PM in Courtroom 6B before Judge Sue L. Robinson. (nmf) (Entered: 12/09/2009).
	D445	MOTION for Leave to File Stipulated Motion for Leave to File a Sur-Reply Brief in Support of MEMC's Motion to Bifurcate - filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Exhibit 1)(Rogowski, Patricia) (Entered: 12/14/2009)
	D446	SUR-REPLY BRIEF re <u>77</u> MOTION to Bifurcate the Issues of Willfulness and Damages for Purposes of Discovery and Trial and proposed Form of Order MEMC's SUR-REPLY BRIEF IN SUPPORT OF ITS MOTION TO BIFURCATE THE ISSUES OF WILLFULNESS AND DAMAGES FOR PURPOSES OF DISCOVERY AND TRIAL filed by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 12/16/2009)
	D447	MOTION for Discovery MOTION FOR THE ADMISSION OF THE EXPERT TESTIMONY OF JOHN T. GOOLKASIAN RELATING TO THE CERTIFICATE OF CORRECTION FOR U.S. PATENT NO. 7,067,396 - filed by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 05/07/2010)
	D448	OPENING BRIEF in Support re <u>141</u> MOTION for Discovery MOTION FOR THE ADMISSION OF THE EXPERT TESTIMONY OF JOHN T. GOOLKASIAN RELATING TO THE CERTIFICATE OF CORRECTION FOR U.S. PATENT NO. 7,067,396 filed by MEMC Electronic Materials Inc..Answering Brief/Response due date per Local Rules is 5/24/2010. (Attachments: # <u>1</u> Exhibit 1, # <u>2</u> Exhibit 2, # <u>3</u> Exhibit 3, # <u>4</u> Exhibit 4, # <u>5</u> Exhibit 5, # <u>6</u> Exhibit 6, # <u>7</u> Exhibit 7, # <u>8</u> Exhibit 8, # <u>9</u> Exhibit 9, # <u>10</u> Exhibit 10, # <u>11</u> Exhibit 11, # <u>12</u> Exhibit 12, # <u>13</u> Exhibit 13, # <u>14</u> Exhibit 14, # <u>15</u> Exhibit 15)(Rogowski, Patricia) (Entered: 05/07/2010)

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	D449	ANSWERING BRIEF in Opposition re <u>141</u> MOTION for Discovery MOTION FOR THE ADMISSION OF THE EXPERT TESTIMONY OF JOHN T. GOOLKASIAN RELATING TO THE CERTIFICATE OF CORRECTION FOR U.S. PATENT NO. 7,067,396 Plaintiff's Answering Brief in Opposition to Defendant's Motion For the Admission of Expert Testimony of John T. Goolkasian filed by SOITEC Silicon On Insulator Technologies SA. Reply Brief due date per Local Rules is 6/4/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 05/24/2010)
	D450	DECLARATION re <u>145</u> Answering Brief in Opposition,, Declaration of Marcus T. Hall in Support of Plaintiff's Answering Brief in Opposition to Defendant's Motion For the Admission of Expert Testimony of John T. Goolkasian by SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Exhibit B, # <u>3</u> Exhibit C, # <u>4</u> Exhibit D, # <u>5</u> Exhibit E, # <u>6</u> Exhibit F, # <u>7</u> Exhibit G, # <u>8</u> Exhibit H, # <u>9</u> Exhibit I, # <u>10</u> Exhibit J, # <u>11</u> Exhibit K, # <u>12</u> Exhibit L, # <u>13</u> Exhibit M, # <u>14</u> Exhibit N, # <u>15</u> Certificate of Service)(Kraft, Denise) (Entered: 05/24/2010)
	D451	REPLY BRIEF IN SUPPORT OF <u>141</u> MOTION for Discovery MOTION FOR THE ADMISSION OF THE EXPERT TESTIMONY OF JOHN T. GOOLKASIAN RELATING TO THE CERTIFICATE OF CORRECTION FOR U.S. PATENT NO. 7,067,396 filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Exhibit 1, # <u>2</u> Exhibit 2, # <u>3</u> Exhibit 3, # <u>4</u> Exhibit 4, # <u>5</u> Exhibit 5, # <u>6</u> Exhibit 6)(Rogowski, Patricia) Modified on 6/4/2010 (lid). (Entered: 06/04/2010)
	D452	STATEMENT re <u>148</u> Stipulation Joint Claim Construction Statement by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/14/2010)
	D453	CLAIM Construction Chart by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/14/2010)
	D454	SUR-REPLY BRIEF re <u>141</u> MOTION for Discovery MOTION FOR THE ADMISSION OF THE EXPERT TESTIMONY OF JOHN T. GOOLKASIAN RELATING TO THE CERTIFICATE OF CORRECTION FOR U.S. PATENT NO. 7,067,396 Surreply by Plaintiffs to Motion by Defendant For The Admission of Expert Testimony of John T. Goolkasian filed by SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/15/2010)
	D455	DECLARATION re <u>157</u> Sur-Reply Brief, Declaration of Marcus T. Hall in Support of Surreply by Plaintiffs to Motion by Defendant For The Admission of Expert Testimony of John T. Goolkasian by SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Exhibit B, # <u>3</u> Exhibit C, # <u>4</u> Exhibit D, # <u>5</u> Certificate of Service)(Kraft, Denise) (Entered: 06/15/2010)

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	D456	CLAIM CONSTRUCTION OPENING BRIEF filed by MEMC Electronic Materials Inc.. (Attachments: # 1 Appendix DA0001-DA0006, # 2 Appendix DA0007-DA0032, # 3 Appendix DA0033-DA0072, # 4 Appendix DA0073-DA0112, # 5 Appendix DA0113-DA0152, # 6 Appendix DA0153-DA0192, # 7 Appendix DA0193-DA0232, # 8 Appendix DA0233-DA0272, # 9 Appendix DA0273-DA0312, # 10 Appendix DA0313-DA0352, # 11 Appendix DA0353-DA0392, # 12 Appendix DA0393-DA0432, # 13 Appendix DA0433-DA0472, # 14 Appendix DA0473-DA0512, # 15 Appendix DA0513-DA0521, # 16 Appendix DA0522-DA0545, # 17 Appendix SEALED - DA0546-DA0551, # 18 Appendix DA0552-DA0563, # 19 Appendix SEALED - DA0564-DA0566, # 20 Appendix DA0567-DA0573, # 21 Appendix SEALED - DA0574-DA0599, # 22 Appendix DA0600-DA0604, # 23 Appendix DA0605-DA0609, # 24 Appendix DA0610-DA0625, # 25 Appendix DA0626-0634, # 26 Appendix DA0635, # 27 Appendix DA0636-DA0652, # 28 Appendix SEALED - DA0653-DA0657, # 29 Appendix DA0658-DA0667, # 30 Appendix DA0668-DA0670, # 31 Appendix DA0671-DA0678, # 32 Appendix DA0679-DA0687, # 33 Appendix DA0688-DA0696, # 34 Appendix SEALED - DA0697-DA0705, # 35 Appendix SEALED - DA0706-DA0711, # 36 Appendix SEALED - DA0712-DA0714, # 37 Appendix DA0715-DA0717, # 38 Appendix DA0718-DA0719, # 39 Appendix DA0720-DA0722, # 40 Appendix DA0723-DA0732, # 41 Appendix DA0733-DA0740, # 42 Appendix DA0741-DA0749, # 43 Appendix DA0750-DA0769, # 44 Appendix DA0770-DA0781)(Rogowski, Patricia) (Entered: 06/25/2010)
	D457	CLAIM CONSTRUCTION OPENING BRIEF Plaintiffs S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Opening Claim Construction Brief filed by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/25/2010)
	D458	DECLARATION re <u>168</u> Claim Construction Opening Brief, Declaration of Marcus T. Hall in Support of Plaintiffs S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Opening Claim Construction Brief by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/25/2010)

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FORM PTO-1449	SERIAL NO. 10/561,299	CASE NO. 9905/34 (BIF023273US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE December 15, 2005	GROUP ART UNIT 2891
(use several sheets if necessary)	APPLICANT(S): Jean-Pierre Joly	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.	
	D459	APPENDIX re <u>167</u> Claim Construction Opening Brief,,,,, by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix DA-0001 - DA-0006, # <u>2</u> Appendix DA-0007 - DA-0032, # <u>3</u> Appendix DA-0033 - DA-0072, # <u>4</u> Appendix DA-0073 - DA-0112, # <u>5</u> Appendix DA-0113 - DA-0152, # <u>6</u> Appendix DA-0153 - DA-0192, # <u>7</u> Appendix DA-0193 - DA-0232, # <u>8</u> Appendix DA-0233 - DA-0272, # <u>9</u> Appendix DA-0273 - DA-0312, # <u>10</u> Appendix DA-0313 - DA-0352, # <u>11</u> Appendix DA-0353 - DA-0392, # <u>12</u> Appendix DA-0393 - DA-0432, # <u>13</u> Appendix DA-0433 - DA-0472, # <u>14</u> Appendix DA-0473 - DA-0512, # <u>15</u> Appendix DA-0513 - DA-0521)(Rogowski, Patricia) (Entered: 06/28/2010)
	D460	REDACTED VERSION of <u>175</u> Appendix by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix DA0522-DA0545, # <u>2</u> Appendix DA0546-DA0551, # <u>3</u> Appendix DA0552-DA0563, # <u>4</u> Appendix DA0564-DA0566, # <u>5</u> Appendix DA0567-DA0573, # <u>6</u> Appendix DA0574-DA0599, # <u>7</u> Appendix DA0600-DA0604, # <u>8</u> Appendix DA0605-DA0609, # <u>9</u> Appendix DA0610-DA0625, # <u>10</u> Appendix DA0626-DA0634, # <u>11</u> Appendix DA0635, # <u>12</u> Appendix DA0636-DA0652, # <u>13</u> Appendix DA0653-DA0657, # <u>14</u> Appendix DA0658-DA0667, # <u>15</u> Appendix DA0668-DA0670, # <u>16</u> Appendix DA0671-DA0678, # <u>17</u> Appendix DA0679-DA0687, # <u>18</u> Appendix DA0688-DA0696, # <u>19</u> Appendix DA0697-DA0705, # <u>20</u> Appendix DA0706-DA0711, # <u>21</u> Appendix DA0712-DA0714, # <u>22</u> Appendix DA0715-DA0717, # <u>23</u> Appendix DA0718-DA0719, # <u>24</u> Appendix DA0720-DA0722, # <u>25</u> Appendix DA0723-DA0732, # <u>26</u> Appendix DA0733-DA0740, # <u>27</u> Appendix DA0741-DA0749, # <u>28</u> Appendix DA0750-DA0769, # <u>29</u> Appendix DA0770-DA0781, # <u>30</u> Certificate of Service)(Rogowski, Patricia) (Entered: 06/28/2010)
	D461	NOTICE of filing the following document(s) in paper format: Joint Appendix of Exhibits to Opening and Answering Claim Construction Briefs (1) Vol. I - JA0001 to JA0533. APPENDIX VOL I. re <u>173</u> Notice of Filing Paper Documents(OVERSIZED DOCUMENT, ITEM ON FILE IN THE CLERKS OFFICE). (lid) (Entered: 06/28/2010).
	D462	NOTICE of filing the following document(s) in paper format: Joint Appendix of Exhibits to Opening and Answering Claim Construction Briefs (2) Vol. II - JA0534 to JA0930. APPENDIX VOL II. re 173 Notice of Filing Paper Documents(OVERSIZED DOCUMENT, ITEM ON FILE IN THE CLERKS OFFICE). (lid) (Entered: 06/28/2010).
	D463	NOTICE of filing the following document(s) in paper format: Joint Appendix of Exhibits to Opening and Answering Claim Construction Briefs (3) Vol. III – JA0931 to JA1502. APPENDIX VOL III. re 173 Notice of Filing Paper Documents(OVERSIZED DOCUMENT, ITEM ON FILE IN THE CLERKS OFFICE) (lid) (Entered: 06/28/2010) (2 parts).

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FORM PTO-1449	SERIAL NO. 10/561,299	CASE NO. 9905/34 (BIF023273US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE December 15, 2005	GROUP ART UNIT 2891
(use several sheets if necessary)	APPLICANT(S): Jean-Pierre Joly	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.	
	D464	NOTICE of filing the following document(s) in paper format: Joint Appendix of Exhibits to Opening and Answering Claim Construction Briefs (4) Vol. IV – JA1503 to JA1510. APPENDIX VOL IV. re <u>173</u> Notice of Filing Paper Documents, (OVERSIZED DOCUMENT, ITEM ON FILE IN THE CLERKS OFFICE) (lid) (Entered: 06/28/2010).
	D465	NOTICE of filing the following document(s) in paper format: Joint Appendix of Exhibits to Opening and Answering Claim Construction Briefs (5) Vol. V – JA1511 to JA2089 (2 parts)
	D466	Vol. VI - JA2090 to JA2557. Original document(s) to be filed with the Clerk's Office. Notice filed by Denise Seastone Kraft on behalf of Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/25/2010).
	D467	MOTION in Limine SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
	D468	MOTION for Partial Summary Judgment of Invalidity of the Asserted Aspar Patent Claims - filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/02/2010)
	D469	OPENING BRIEF in Support re <u>186</u> MOTION in Limine SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
	D470	OPENING BRIEF in Support re <u>187</u> MOTION for Partial Summary Judgment of Invalidity of the Asserted Aspar Patent Claims filed by MEMC Electronic Materials Inc.. Answering Brief/Response due date per Local Rules is 7/19/2010. (Rogowski, Patricia) (Entered: 07/02/2010)

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(use several sheets if necessary)		APPLICANT(S): Jean-Pierre Joly

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	D471	APPENDIX re <u>186</u> MOTION in Limine SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony Plaintiffs' Omnibus Appendix to Daubert Motion and Motions For Partial Summary Judgment Filed on July 2, 2010 by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Appendix Vol. II of XIX, # <u>2</u> Appendix Vol. III of XIX, # <u>3</u> Appendix Vol. IV of XIX, # <u>4</u> Appendix Vol. V of XIX, # <u>5</u> Appendix Vol. VII of XIX, # <u>6</u> Appendix Vol. IX of XIX, # <u>7</u> Appendix Vol. XI of XIX, # <u>8</u> Appendix Vol. XII of XIX, # <u>9</u> Appendix Vol. XIII of XIX, # <u>10</u> Appendix Vol. XIV of XIX, # <u>11</u> Appendix Vol. XV of XIX, # <u>12</u> Appendix Vol. XVI of XIX, # <u>13</u> Appendix Vol. XVIII of XIX, # <u>14</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
	D472	MOTION for Summary Judgment of Non-Infringement - filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/02/2010)
	D473	MOTION for Partial Summary Judgment SOITEC/CEA Parties Motion For Partial Summary Judgment That The Patents in Suit Satisfy The Written Description Requirement - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
	D474	OPENING BRIEF in Support re <u>202</u> MOTION for Partial Summary Judgment SOITEC/CEA Parties Motion For Partial Summary Judgment That The Patents in Suit Satisfy The Written Description Requirement filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc..Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
	D475	MOTION for Partial Summary Judgment Plaintiffs' Motion For Partial Summary Judgment That The Certificate of Correction For the '396 Patent is Valid - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
	D476	OPENING BRIEF in Support re <u>204</u> MOTION for Partial Summary Judgment Plaintiffs' Motion For Partial Summary Judgment That The Certificate of Correction For the '396 Patent is Valid filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA.Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)

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	D477	MOTION for Partial Summary Judgment SOITEC/CEA Parties' Motion For Partial Summary Judgment That The Aspar Patents Are Not Invalid For Inequitable Conduct - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
	D478	OPENING BRIEF in Support re <u>206</u> MOTION for Partial Summary Judgment SOITEC/CEA Parties' Motion For Partial Summary Judgment That The Aspar Patents Are Not Invalid For Inequitable Conduct filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
	D479	MOTION for Partial Summary Judgment Plaintiffs' Motion For Partial Summary Judgment That The Bruel Patent Does Not Anticipate The Aspar Patents - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
	D480	OPENING BRIEF in Support re <u>208</u> MOTION for Partial Summary Judgment Plaintiffs' Motion For Partial Summary Judgment That The Bruel Patent Does Not Anticipate The Aspar Patents filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
	D481	MOTION for Partial Summary Judgment SOITEC's Motion For Partial Summary Judgment of Invalidity of United States Patent No. 5,834,812 For Lack of Enablement - filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
	D482	OPENING BRIEF in Support re <u>210</u> MOTION for Partial Summary Judgment SOITEC's Motion For Partial Summary Judgment of Invalidity of United States Patent No. 5,834,812 For Lack of Enablement filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
	D483	MOTION for Partial Summary Judgment SOITEC's Motion For Partial Summary Judgment For Invalidity of Asserted Claims of United States Patent No. 5,834,812 in View of Prior Art - filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)

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LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE December 15, 2005	GROUP ART UNIT 2891
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EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.	
	D484	MOTION for Partial Summary Judgment That the Best Mode Requirement is Satisfied for the Claims of the '009 and '396 Patents - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Reed, John) (Entered: 07/02/2010)
	D485	OPENING BRIEF in Support re <u>212</u> MOTION for Partial Summary Judgment SOITEC's Motion For Partial Summary Judgment For Invalidity of Asserted Claims of United States Patent No. 5,834,812 in View of Prior Art filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
	D486	OPENING BRIEF in Support re <u>213</u> MOTION for Partial Summary Judgment That the Best Mode Requirement is Satisfied for the Claims of the '009 and '396 Patents filed by SOITEC Silicon On Insulator Technologies SA. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Reed, John) (Entered: 07/02/2010)
	D487	REDACTED VERSION of <u>200</u> Opening Brief in Support, by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/07/2010)
	D488	REDACTED VERSION of <u>201</u> Appendix by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix MA0001 - MA0004, # <u>2</u> Appendix MA0005 - MA0010, # <u>3</u> Appendix MA0011 - MA0016, # <u>4</u> Appendix MA0017 - MA0020, # <u>5</u> Appendix MA0021 - MA0029, # <u>6</u> Appendix MA0030 - MA0045, # <u>7</u> Appendix MA0046 - MA0052, # <u>8</u> Appendix MA0053 - MA0078, # <u>9</u> Appendix MA0079 - MA0092, # <u>10</u> Appendix MA0093 - MA0129, # <u>11</u> Appendix MA0130 - MA0148, # <u>12</u> Appendix MA0149 - MA0160, # <u>13</u> Appendix MA0161 - MA0163, # <u>14</u> Appendix MA0164 - MA0167, # <u>15</u> Appendix MA0168 - MA0172, # <u>16</u> Appendix MA0173 - MA0183, # <u>17</u> Appendix MA0184 - MA0196, # <u>18</u> Appendix MA0197 - MA0207, # <u>19</u> Appendix MA0208 - MA0241, # <u>20</u> Appendix MA0242 - MA0245, # <u>21</u> Appendix MA0246 - MA0249, # <u>22</u> Appendix MA0250 - MA0252, # <u>23</u> Appendix MA0253 - MA0265, # <u>24</u> Appendix MA0266 - MA0281, # <u>25</u> Appendix MA0282 - MA0312, # <u>26</u> Appendix MA0313 - MA0359, # <u>27</u> Appendix MA0360 - MA0365, # <u>28</u> Appendix MA0366, # <u>29</u> Appendix MA0367 - MA0400, # <u>30</u> Appendix MA0401 - MA0474, # <u>31</u> Appendix MA0475 - MA0483, # <u>32</u> Certificate)(Rogowski, Patricia) (Entered: 07/07/2010)

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D489	REDACTED VERSION of <u>190</u> Appendix by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix MA0484 - MA0489, # <u>2</u> Appendix MA0490 - MA0515, # <u>3</u> Appendix MA0516 - MA0534, # <u>4</u> Appendix MA0535 - MA0541, # <u>5</u> Appendix MA0542 - MA0550, # <u>6</u> Appendix MA0551 - MA0561, # <u>7</u> Appendix MA0562 - MA0564, # <u>8</u> Appendix MA0565 - MA0569, # <u>9</u> Appendix MA0570 - MA0574, # <u>10</u> Appendix MA0575 - MA0576, # <u>11</u> Appendix MA0577 - MA0601, # <u>12</u> Appendix MA0602 - MA0603, # <u>13</u> Appendix MA0604 - MA0605, # <u>14</u> Appendix MA0606 - MA0609, # <u>15</u> Appendix MA0610 - MA0612, # <u>16</u> Appendix MA0613 - MA0625, # <u>17</u> Appendix MA0626 - MA0628, # <u>18</u> Appendix MA0629 - MA0630, # <u>19</u> Appendix MA0631 - MA0653, # <u>20</u> Appendix MA0654 - MA0685, # <u>21</u> Appendix MA0686 - MA0701, # <u>22</u> Appendix MA0702 - MA0732, # <u>23</u> Appendix MA0733 - MA0742, # <u>24</u> Appendix MA0743 - MA0750, # <u>25</u> Appendix MA0751 - MA0766, # <u>26</u> Appendix MA0767 - MA0772, # <u>27</u> Appendix MA0773 - MA0780, # <u>28</u> Appendix MA0781 - MA0807, # <u>29</u> Appendix MA0808 - MA0824, # <u>30</u> Appendix MA0825 - MA0831.1, # <u>31</u> Appendix MA0832 - MA0838, # <u>32</u> Appendix MA0839 - MA0844, # <u>33</u> Appendix MA0845 - MA0858, # <u>34</u> Appendix MA0859 - MA0868, # <u>35</u> Appendix MA0869 - MA0877, # <u>36</u> Appendix MA0878 - MA0884, # <u>37</u> Appendix MA0885 - MA0887, # <u>38</u> Appendix MA0888 - MA0891, # <u>39</u> Appendix MA0892 - MA0909, # <u>40</u> Appendix MA0910 - MA0931, # <u>41</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/07/2010)
D490	REDACTED VERSION of <u>198</u> Opening Brief in Support,, SOITEC/CEA Parties' Opening Brief In Support Of Motion For Summary Judgment: Non-Infringement by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 07/08/2010)
D491	REDACTED VERSION of <u>197</u> SEALED MOTION for Summary Judgment SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement (FILED UNDER SEAL)SEALED MOTION for Summary Judgment SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement (FILED UNDER SEAL) SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 07/08/2010)
D492	REDACTED VERSION of <u>192</u> Appendix, Plaintiffs' Omnibus Appendix to Daubert Motion And Motions For Partial Summary Judgment Filed on July 2, 2010 - Volume VI of XIX by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 07/09/2010)
D493	REDACTED VERSION of <u>193</u> Appendix, Plaintiffs' Omnibus Appendix to Daubert Motion And Motions For Partial Summary Judgment Filed on July 2, 2010 - Volume VIII of XIX by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 07/09/2010)

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(use several sheets if necessary)		APPLICANT(S): Jean-Pierre Joly

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	D494	REDACTED VERSION of <u>194</u> Appendix, Plaintiffs' Omnibus Appendix to Daubert Motion And Motions For Partial Summary Judgment Filed on July 2, 2010 - Volume X of XIX by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 07/09/2010)
	D495	REDACTED VERSION of <u>195</u> Appendix, Plaintiffs' Omnibus Appendix to Daubert Motion And Motions For Partial Summary Judgment Filed on July 2, 2010 - Volume XVII of XIX by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 07/09/2010)
	D496	REDACTED VERSION of <u>196</u> Appendix, Plaintiffs' Omnibus Appendix to Daubert Motion And Motions For Partial Summary Judgment Filed on July 2, 2010 - Volume XIX of XIX by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 07/09/2010)
	D497	CLAIM CONSTRUCTION ANSWERING BRIEF re <u>168</u> Claim Construction Opening Brief, filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/09/2010)
	D498	APPENDIX re <u>228</u> Claim Construction Answering Brief by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix DA0782_DA0783, # <u>2</u> Appendix DA0784 - DA0785, # <u>3</u> Appendix DA0786, # <u>4</u> Appendix DA0787 - DA0810, # <u>5</u> Appendix DA0811 - DA0834, # <u>6</u> Appendix DA0835 - DA0845, # <u>7</u> Appendix DA0846 - DA0855, # <u>8</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/09/2010)
	D499	CLAIM CONSTRUCTION ANSWERING BRIEF re <u>168</u> Claim Construction Opening Brief, <u>228</u> Claim Construction Answering Brief Plaintiffs S.O.I.TEC On Insulator Technologies, S.A. And Commissariat A Energie Atomique's Answering Claim Construction Brief filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/09/2010)
	D500	APPENDIX re <u>230</u> Claim Construction Answering Brief, Appendix to Plaintiffs S.O.I.TEC On Insulator Technologies, S.A. And Commissariat A Energie Atomique's Answering Claim Construction Brief by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Appendix PA-0001 - PA-0050, # <u>2</u> Appendix PA-0051 - PA-0083, # <u>3</u> Certificate of Service)(Kraft, Denise) (Entered: 07/09/2010)
	D501	REDACTED VERSION of <u>183</u> Appendix, Joint Appendix of Exhibits to Opening and Answering Claim Construction Briefs Volume IV of VI by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 07/12/2010)

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	D502	REDACTED VERSION of <u>170</u> Exhibit to a Document, Exhibit A to Declaration of Marcus T. Hall in Support of Plaintiffs S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Opening Claim Construction Brief by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 07/12/2010)
	D503	REDACTED VERSION of <u>171</u> Exhibit to a Document, Exhibit B to Declaration of Marcus T. Hall in Support of Plaintiffs S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Opening Claim Construction Brief by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 07/12/2010)
	D504	REDACTED VERSION of <u>172</u> Exhibit to a Document, Exhibit C to Declaration of Marcus T. Hall in Support of Plaintiffs S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Opening Claim Construction Brief by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 07/12/2010)
	D505	ANSWERING BRIEF in Opposition re <u>186</u> MOTION in Limine SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010)
	D506	ANSWERING BRIEF in Opposition re <u>208</u> MOTION for Partial Summary Judgment Plaintiffs' Motion For Partial Summary Judgment That The Bruel Patent Does Not Anticipate The Aspar Patents filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010)
	D507	ANSWERING BRIEF in Opposition re <u>202</u> MOTION for Partial Summary Judgment SOITEC/CEA Parties Motion For Partial Summary Judgment That The Patents in Suit Satisfy The Written Description Requirement filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010)
	D508	ANSWERING BRIEF in Opposition re <u>204</u> MOTION for Partial Summary Judgment Plaintiffs' Motion For Partial Summary Judgment That The Certificate of Correction For the '396 Patent is Valid filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010)
	D509	ANSWERING BRIEF in Opposition re <u>210</u> MOTION for Partial Summary Judgment SOITEC's Motion For Partial Summary Judgment of Invalidity of United States Patent No. 5,834,812 For Lack of Enablement filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010)

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(use several sheets if necessary)	APPLICANT(S): Jean-Pierre Joly	

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	D510	ANSWERING BRIEF in Opposition re <u>212</u> MOTION for Partial Summary Judgment SOITEC's Motion For Partial Summary Judgment For Invalidity of Asserted Claims of United States Patent No. 5,834,812 in View of Prior Art filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010)
	D511	APPENDIX re <u>247</u> Answering Brief in Opposition,, Appendix To Plaintiffs' Answering Brief In Opposition To Defendant's Motion For Partial Summary Judgment Of Invalidity Of The Asserted Aspar Claims (PA-1103 - PA-1156) by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # 1 Exhibit PA-1103 - PA-1109 - FILED UNDER SEAL, # 2 Exhibit PA-1110 - PA-1118 - FILED UNDER SEAL, # 3 Exhibit PA-1119 - PA-1130 - FILED UNDER SEAL, # 4 Exhibit PA-1131 - PA-1143 - FILED UNDER SEAL, # <u>5</u> Exhibit PA-1144 - PA-1156, # <u>6</u> Certificate of Service)(Kraft, Denise) (Entered: 07/19/2010)
	D512	APPENDIX re <u>250</u> Answering Brief in Opposition, Appendix to Plaintiffs' Answering Brief in Opposition to Defendant's Motion For Summary Judgment of Non-Infringement by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Exhibit PA-1190 - PA-1191, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 07/19/2010)
	D513	REDACTED VERSION of <u>241</u> Answering Brief in Opposition, to Plaintiffs' Motion for Partial Summary Judgment that the Best Mode Requirement is Satisfied for the Claims of the '009 and '396 Patents by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 07/26/2010)
	D514	REDACTED VERSION of <u>249</u> Answering Brief in Opposition, to Plaintiffs' Motion for Summary Judgment on the Infringement of U.S. Patent No. 5,834,812 by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 07/26/2010)
	D515	REDACTED VERSION of <u>253</u> Answering Brief in Opposition, to Plaintiffs' Motion for Partial Summary Judgment that the Aspar Patents Are Not Invalid for Inequitable Conduct by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 07/26/2010)

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	D516	REDACTED VERSION of <u>240</u> Appendix by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix MA0932 - MA0985, # <u>2</u> Appendix MA0986 - MA1039.22, # <u>3</u> Appendix MA1040 - MA1144, # <u>4</u> Appendix MA1145 - MA1200, # <u>5</u> Appendix MA1201 - MA1265, # <u>6</u> Appendix MA1265.1 - MA1338, # <u>7</u> Appendix MA1339 - MA1547, # <u>8</u> Appendix MA1548 - MA1627, # <u>9</u> Appendix MA1628 - MA1693, # <u>10</u> Appendix MA1694 - MA1953, # <u>11</u> Appendix MA1954 - MA2127, # <u>12</u> Appendix MA2128 - MA2206, # <u>13</u> Appendix MA2207 - MA2253, # <u>14</u> Appendix MA2254 - MA2273, # <u>15</u> Appendix MA2274 - MA2333, # <u>16</u> Appendix MA2334 - MA2337, # <u>17</u> Appendix MA2338 - MA2342, # <u>18</u> Appendix MA2343 - MA2346, # <u>19</u> Appendix MA2347 - MA2351, # <u>20</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/26/2010) (2 parts).
	D517	REDACTED VERSION of <u>261</u> Answering Brief in Opposition, to Plaintiffs' Motion for Partial Summary Judgment that the Best Mode Requirement is Satisfied for the Claims of the '009 and '396 Patents (CORRECTED VERSION OF D.I. 241) by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 07/26/2010)
	D518	REDACTED VERSION of <u>250</u> Answering Brief in Opposition, to Soitec's Brief in Opposition to Defendant's Motion For Summary Judgment of Non-Infringement by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/26/2010)
	D519	REDACTED VERSION of <u>247</u> Answering Brief in Opposition,, to Plaintiffs' Answering Brief In Opposition To Defendant's Motion For Partial Summary Judgment Of In validity Of The Asserted Aspar Claims by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/26/2010)
	D520	REDACTED VERSION of <u>254</u> Appendix,, to Appendix To Plaintiffs' Answering Brief In Opposition To Defendant's Motion For Partial Summary Judgment Of Invalidity Of The Asserted Aspar Claims (PA-1103 - PA-1143 by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 07/26/2010)
	D521	REDACTED VERSION of <u>251</u> Appendix,, to Appendix to Plaintiffs' Answering Brief in Opposition to Defendant's Motion For Summary Judgment of Non-Infringement by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 07/26/2010)

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	D522	REPLY BRIEF re <u>204</u> MOTION for Partial Summary Judgment Plaintiffs' Motion For Partial Summary Judgment That The Certificate of Correction For the '396 Patent is Valid Reply Brief in Support of Plaintiffs' Motion For Partial Summary Judgment That The Certificate of Correction For the '396 Patent is Valid filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
	D523	DECLARATION re <u>268</u> Reply Brief, Declaration of Marcus T. Hall in Support of Reply Brief in Support of Plaintiffs' Motion For Partial Summary Judgment That The Certificate of Correction For the '396 Patent is Valid by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
	D524	APPENDIX re <u>268</u> Reply Brief, Omnibus Appendix to Plaintiffs' Reply Briefs in Support of Plaintiffs' Daubert Motion and Motions For Partial Summary Judgment (PA-1192 - PA-1261) by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Exhibit PA-1199 - PA-1204, # <u>2</u> Exhibit PA-1205 - PA-1206, # <u>3</u> Exhibit PA-1206.1, # <u>4</u> Exhibit PA-1231 - PA-1237, # <u>5</u> Exhibit PA-1238 - PA-1245, # <u>6</u> Exhibit PA-1246 - PA-1257, # <u>7</u> Exhibit PA-1258 - PA-1261, # <u>8</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
	D525	REPLY BRIEF re <u>210</u> MOTION for Partial Summary Judgment SOITEC's Motion For Partial Summary Judgment of Invalidity of United States Patent No. 5,834,812 For Lack of Enablement Reply Brief in Support of SOITEC's Motion For Partial Summary Judgment of Invalidity of United States Patent No. 5,834,812 For Lack of Enablement filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
	D526	REPLY BRIEF re <u>212</u> MOTION for Partial Summary Judgment SOITEC's Motion For Partial Summary Judgment For Invalidity of Asserted Claims of United States Patent No. 5,834,812 in View of Prior Art Reply Brief in Support of SOITEC's Motion For Partial Summary Judgment For Invalidity of Asserted Claims of United States Patent No. 5,834,812 in View of Prior Art filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Exhibit B, # <u>3</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
	D527	REPLY BRIEF re <u>202</u> MOTION for Partial Summary Judgment SOITEC/CEA Parties Motion For Partial Summary Judgment That The Patents in Suit Satisfy The Written Description Requirement Reply Brief in Support of SOITEC/CEA Parties' Motion For Partial Summary Judgment That The Patents in Suit Satisfy The Written Description Requirement filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)

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	D528	REDACTED VERSION of <u>269</u> Appendix, TO REPLY BRIEF IN SUPPORT OF MEMC's MOTION FOR PARTIAL SUMMARY JUDGMENT OF INVALIDITY OF THE ASSERTED ASPAR PATENT CLAIMS by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix Table of Contents, # <u>2</u> Appendix MA2453_MA2479, # <u>3</u> Certificate of Service)(Rogowski, Patricia) (Entered: 08/03/2010)
	D529	REDACTED VERSION of <u>273</u> Appendix REPLY BRIEF IN SUPPORT OF MEMC's MOTION FOR SUMMARY JUDGMENT OF NON-INFRINGEMENT by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix Table of Contents, # <u>2</u> Appendix MA2352 - MA2361, # <u>3</u> Appendix MA2362 - MA2371, # <u>4</u> Appendix MA2372 - MA2381, # <u>5</u> Appendix MA2382 - MA2391, # <u>6</u> Appendix MA2392 - MA2399, # <u>7</u> Appendix MA2400 - MA2404, # <u>8</u> Appendix MA2405 - MA2422, # <u>9</u> Appendix MA2423 - MA2425, # <u>10</u> Appendix MA2426 - MA2427, # <u>11</u> Appendix MA2428 - MA2430, # <u>12</u> Appendix MA2431 - MA2440, # <u>13</u> Appendix MA2441 - MA2448, # <u>14</u> Appendix MA2449 - MA2452, # <u>15</u> Appendix MA2452.1 - MA2452.9, # <u>16</u> Certificate of Service)(Rogowski, Patricia) (Entered: 08/03/2010)
	D530	REDACTED VERSION of <u>267</u> Reply Brief IN SUPPORT OF MEMC's MOTION FOR PARTIAL SUMMARY JUDGMENT OF INVALIDITY OF THE ASSERTED ASPAR PATENT CLAIMS by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 08/03/2010)
	D531	REDACTED VERSION of <u>271</u> Reply Brief IN SUPPORT OF MEMC's MOTION FOR SUMMARY JUDGMENT OF NON-INFRINGEMENT by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 08/03/2010)
	D532	REDACTED VERSION of <u>274</u> Appendix,, Omnibus Appendix to Plaintiffs' Reply Briefs in Support of Plaintiffs' Daubert Motion and Motions For Partial Summary Judgment (PA-1192 - PA-1198 and PA-1207 - PA-1230 Filed Under Seal) by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 08/06/2010)
	D533	REDACTED VERSION of <u>277</u> Reply Brief, in Support of SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 08/06/2010)
	D534	REDACTED VERSION of <u>278</u> Reply Brief,, in Support of SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement (Filed Under Seal) by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 08/06/2010)

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	D535	REDACTED VERSION of <u>279</u> Reply Brief,, in Support of Plaintiffs' Motion for Partial Summary Judgment That the Best Mode Requirement is Satisfied for the Claims of the '009 and '396 Patents (Filed Under Seal) by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 08/06/2010)
	D536	REDACTED VERSION of <u>281</u> Reply Brief, in Support of Plaintiffs' Motion For Partial Summary Judgment That The Bruel Patent Does Not Anticipate The Aspar Patents (Filed Under Seal) by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 08/06/2010)
	D537	REDACTED VERSION of <u>282</u> Reply Brief,, in Support of SOITEC/CEA Parties' Motion For Partial Summary Judgment That The Aspar Patents Are Not Invalid For Inequitable Conduct (Filed Under Seal) by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 08/06/2010)
	D538	NOTICE OF SERVICE of CD of documents MEMC0782194-MEMC0782500 and FH-1 0001 - FH-8 0067 by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 09/16/2010)
	D539	REDACTED VERSION of <u>301</u> SEALED MOTION for Reconsideration Request to Modify Protective Order by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 09/24/2010)
	D540	REDACTED VERSION of <u>302</u> Declaration, of Michael L. Brody in Support of Motion to Reconsider Request to Modify Protective Order by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 09/24/2010)
	D541	REDACTED VERSION of <u>303</u> Exhibit to a Document Exhibit A to Michael L. Brody in Support of Motion to Reconsider Request to Modify Protective Order by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 09/24/2010)
	D542	REDACTED VERSION of <u>304</u> Exhibit to a Document Exhibit B to Michael L. Brody in Support of Motion to Reconsider Request to Modify Protective Order by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 09/24/2010)

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	D543	REDACTED VERSION of <u>305</u> Exhibit to a Document Exhibit C to Michael L. Brody in Support of Motion to Reconsider Request to Modify Protective Order by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 09/24/2010)
	D544	REDACTED VERSION of <u>306</u> Exhibit to a Document Exhibit D to Michael L. Brody in Support of Motion to Reconsider Request to Modify Protective Order by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 09/24/2010)
	D545	Proposed Pretrial Order [Proposed] Joint Pretrial Order (FILED UNDER SEAL) by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Exhibit 1 (Sealed), # <u>2</u> Exhibit 2A (Sealed), # <u>3</u> Exhibit 2B (Sealed), # <u>4</u> Exhibit 3A (Sealed), # <u>5</u> Exhibit 3B (Sealed), # <u>6</u> Exhibit 4A (Sealed), # <u>7</u> Exhibit 4B (Sealed), # <u>8</u> Exhibit 4C (Sealed), # <u>9</u> Exhibit 5A (Sealed), # <u>10</u> Exhibit 5B (Sealed), # <u>11</u> Exhibit 6A (Sealed), # <u>12</u> Exhibit 6B (Sealed), # <u>13</u> Exhibit 7A (Sealed), # <u>14</u> Exhibit 7B (Sealed), # <u>15</u> Certificate of Service)(Kraft, Denise) (Entered: 10/07/2010)
	D546	Proposed Voir Dire by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Certificate of Service)(Rogowski, Patricia) (Entered: 10/08/2010)
	D547	VERDICT SHEET by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Certificate of Service)(Rogowski, Patricia) (Entered: 10/08/2010)
	D548	Proposed Voir Dire by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 10/08/2010)
	D549	VERDICT SHEET by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 10/08/2010)
	D550	Proposed Jury Instructions by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 10/08/2010)
	D551	Proposed Jury Instructions by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 10/08/2010)

EXAMINER	DATE CONSIDERED
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FORM PTO-1449	SERIAL NO. 10/561,299	CASE NO. 9905/34 (BIF023273US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE December 15, 2005	GROUP ART UNIT 2891
(use several sheets if necessary)		APPLICANT(S): Jean-Pierre Joly

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.	
	D552	REDACTED VERSION of <u>315</u> Proposed Pretrial Order,, Redacted Version of [Proposed] Joint Pretrial Order by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Exhibit 1, # <u>2</u> Exhibit 2A, # <u>3</u> Exhibit 2B, # <u>4</u> Exhibit 3A, # <u>5</u> Exhibit 3B, # <u>6</u> Exhibit 4A, # <u>7</u> Exhibit 4B, # <u>8</u> Exhibit 4C, # <u>9</u> Exhibit 5A, # <u>10</u> Exhibit 5B, # <u>11</u> Exhibit 6A, # <u>12</u> Exhibit 6B, # <u>13</u> Exhibit 7A, # <u>14</u> Exhibit 7B, # <u>15</u> Certificate of Service)(Kraft, Denise) (Entered: 10/13/2010)
	D553	MEMORANDUM OPINION. Signed by Judge Sue L. Robinson on 10/13/2010. (nmf) (Entered: 10/13/2010)
	D554	ORDER denying <u>141</u> Motion for Discovery; denying <u>186</u> Motion in Limine; granting in part and denying in part <u>187</u> Motion for Partial Summary Judgment; granting <u>197</u> Motion for Summary Judgment ; granting <u>199</u> Motion for Summary Judgment ; granting <u>202</u> Motion for Partial Summary Judgment; denying <u>204</u> Motion for Partial Summary Judgment; denying <u>206</u> Motion for Partial Summary Judgment; granting in part and denying in part <u>208</u> Motion for Partial Summary Judgment; denying <u>210</u> Motion for Partial Summary Judgment; denying <u>212</u> Motion for Partial Summary Judgment; granting in part and denying in part <u>213</u> Motion for Partial Summary Judgment. Signed by Judge Sue L. Robinson on 10/13/2010. (nmf) (Entered: 10/13/2010)
	D555	MEMORANDUM ORDER re: claim construction. Signed by Judge Sue L. Robinson on 10/13/2010. (nmf) (Entered: 10/13/2010) ORAL ORDER by Judge Sue L. Robinson on 10/14/2010 that the responses to the issues raised in the exhibits to the joint pre-trial order are to be stricken from the record. (These filings, formerly D.I. Nos. 318 and 323 have been deleted from the docket.) (nmf) (Entered: 10/14/2010)
	D556	AMENDED ORDER denying <u>141</u> Motion for Discovery; denying <u>186</u> Motion in Limine; granting in part and denying in part <u>187</u> Motion for Partial Summary Judgment; granting <u>197</u> Motion for Summary Judgment ; granting <u>199</u> Motion for Summary Judgment ; granting <u>202</u> Motion for Partial Summary Judgment; denying <u>204</u> Motion for Partial Summary Judgment; denying <u>206</u> Motion for Partial Summary Judgment; granting in part and denying in part <u>208</u> Motion for Partial Summary Judgment; denying <u>210</u> Motion for Partial Summary Judgment; denying <u>212</u> Motion for Partial Summary Judgment; *granting* <u>213</u> Motion for Partial Summary Judgment. Signed by Judge Sue L. Robinson on 10/14/2010. (nmf) (Entered: 10/14/2010) Minute Entry for proceedings held before Judge Sue L. Robinson - Final Pretrial Conference held on 10/14/2010. (Court Reporter V. Gunning.) (nmf) (Entered: 10/15/2010) SO ORDERED, re <u>315</u> Proposed Pretrial Order. Signed by Judge Sue L. Robinson on 10/14/2010. (nmf) (Entered: 10/15/2010)

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FORM PTO-1449	SERIAL NO. 10/561,299	CASE NO. 9905/34 (BIF023273US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE December 15, 2005	GROUP ART UNIT 2891
(use several sheets if necessary)	APPLICANT(S): Jean-Pierre Joly	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.	
	D557	MOTION for Reargument re <u>327</u> Memorandum and Order - Reargument of Claim Construction of One Claim Term of U.S. Patent 6,809,009 - filed by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 10/18/2010)
	D558	SECOND AMENDED ORDER re: <u>325</u> denying <u>141</u> Motion for Discovery; denying <u>186</u> Motion in Limine; granting in part and denying in part <u>187</u> Motion for Partial Summary Judgment; granting <u>197</u> Motion for Summary Judgment ; granting <u>199</u> Motion for Summary Judgment **with respect to the '484 patent and with respect to its current process, and denied in other respects; granting <u>202</u> Motion for Partial Summary Judgment; denying <u>204</u> Motion for Partial Summary Judgment; denying <u>206</u> Motion for Partial Summary Judgment; granting in part and denying in part <u>208</u> Motion for Partial Summary Judgment; denying <u>210</u> Motion for Partial Summary Judgment; denying <u>212</u> Motion for Partial Summary Judgment; granting <u>213</u> Motion for Partial Summary Judgment. Signed by Judge Sue L. Robinson on 10/19/2010. (nmf) (Entered: 10/19/2010)
	D559	MEMORANDUM ORDER granting <u>329</u> MOTION for Reargument re <u>327</u> Memorandum and Order - Reargument of Claim Construction of One Claim Term of U.S. Patent 6,809,009. Signed by Judge Sue L. Robinson on 10/19/2010. (nmf) (Entered: 10/19/2010)
	D560	STIPULATION MEMC's Declaratory Judgment counterclaim asserting invalidity of United States Reissued Patent No. 39,484 in Civil Action No. 1:08-292-SLR is dismissed without prejudice by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (nmf,). (Entered: 10/21/2010)
	D561	STIPULATION of Fact re <u>331</u> Memorandum and Order, <u>327</u> Memorandum and Order, <u>325</u> Memorandum Opinion by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 10/21/2010)
	D562	Letter to The Honorable Sue L. Robinson from Denise Seastone Kraft regarding Mutually agreed upon narrowing of the issues for trial - re <u>333</u> Stipulation, <u>332</u> Stipulation,. (Kraft, Denise) (Entered: 10/21/2010) CORRECTING ENTRY: The pdf of D.I. <u>332</u> has been replaced with the correct pdf of the stipulation per request of filer. (nmf) (Entered: 10/22/2010) SO ORDERED, re <u>333</u> Stipulation filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a LEnergie Atomique, <u>332</u> Stipulation, filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a LEnergie Atomique. Signed by Judge Sue L. Robinson on 10/22/2010. (nmf) (Entered: 10/22/2010)
	D563	Voir Dire Questions. Read in Open Court 10/25/2010.(nmf) (Entered: 10/25/2010)

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FORM PTO-1449	SERIAL NO. 10/561,299	CASE NO. 9905/34 (BIF023273US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE December 15, 2005	GROUP ART UNIT 2891
(use several sheets if necessary)	APPLICANT(S): Jean-Pierre Joly	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.	
	D564	Preliminary Jury Instructions. Read in Open Court 10/25/2010. (nmf) (Entered: 10/25/2010) Minute Entry for proceedings held before Judge Sue L. Robinson: Jury Trial Day 1 held on 10/25/2010. (Court Reporter Valerie Gunning, Brian Gaffigan.) (dlk) (Entered: 10/26/2010)
	D565	PLAINTIFF'S BENCH MEMORANDUM. Filed in Court 10/26/2010. (nmf) (Entered: 10/26/2010) Minute Entry for proceedings held before Judge Sue L. Robinson - Jury Trial (Day 2) held on 10/26/2010. (Court Reporter Valerie Gunning, Kevin Maurer.) (dlk) (Entered: 10/26/2010) Minute Entry for proceedings held before Judge Sue L. Robinson - Jury Trial - Day 3, held on 10/27/2010. (Court Reporter Valerie Gunning/Kevin Maurer.) (nms) (Entered: 10/27/2010)
	D566	STATEMENT -- BENCH MEMORANDUM SUPPORTING MEMC'S PROFFER OF ADMISSIONS BY SOITEC IN PRIOR LAWSUIT INVOLVING THE '564 PATENT submitted at trial by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Exhibit A)(Rogowski, Patricia) (Entered: 10/28/2010) Minute Entry for proceedings held before Judge Sue L. Robinson - Jury Trial - Day 4 held on 10/28/2010. (Court Reporter Valerie Gunning/Kevin Maurer.) (nms) (Entered: 11/01/2010)
	D567	Final Jury Instructions read in open Court by Judge Robinson. (lid) (Entered: 11/01/2010) Minute Entry for proceedings held before Judge Sue L. Robinson - Jury Trial held on 11/1/2010. (DAY 5) (Court Reporter V. Gunning.) (lid) (Entered: 11/02/2010) Minute Entry for proceedings held before Judge Sue L. Robinson - Jury Trial completed on 11/2/2010. (DAY 6) (Court Reporter V. Gunning.) (lid) (Entered: 11/02/2010)
	D568	REDACTED VERSION of <u>342</u> Jury Verdict. (lid) (Entered: 11/02/2010)
	D569	STATEMENT Bench Memorandum in Support of Plaintiffs' Motion For Judgment as a Matter of Law of No Unenforceability of the '009 Patent Due To Inequitable Conduct submitted at trial by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 11/02/2010)
	D570	ANSWERING BRIEF in Opposition re <u>301</u> SEALED MOTION for Reconsideration Request to Modify Protective Order (MEMC'S OPPOSITION TO PLAINTIFFS' MOTION FOR REARGUMENT RE: MODIFICATION OF THE PROTECTIVE ORDER) filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 11/22/2010. (Attachments: # <u>1</u> Exhibit 1 through 5, # <u>2</u> Certificate of Service)(Rogowski, Patricia) (Entered: 11/12/2010)

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FORM PTO-1449	SERIAL NO. 10/561,299	CASE NO. 9905/34 (BIF023273US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE December 15, 2005	GROUP ART UNIT 2891
(use several sheets if necessary)	APPLICANT(S): Jean-Pierre Joly	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.	
	D571	JUDGMENT in favor of defendant MEMC Electronic Materials, Inc. and against plaintiffs S.O.I.TEC Silicon On Insulator Technologies, S.A. and Commissariat A LEnergie Atomique et aux Energies Alternatives as to the 812 patent. IT IS FURTHER ORDERED that judgment be and is hereby entered in favor of plaintiffs S.O.I.TEC Silicon On Insulator Technologies, S.A. and Commissariat A LEnergie Atomique et aux Energies Alternatives and against defendant MEMC Electronic Materials, Inc. as to the 009 patent. Signed by Judge Sue L. Robinson on 11/15/2010. (nmf) (Entered: 11/15/2010)
	D572	STIPULATION Setting Post-Trial Briefing Schedule re <u>348</u> Judgment,, by Commissariat a LEnergie Atomique, MEMC Electronic Materials Inc., SOITEC Silicon On Insulator Technologies SA. (Rogowski, Patricia) (Entered: 11/15/2010)
	D573	MOTION for Reargument re <u>348</u> Judgment,, (MEMCS MOTION FOR REARGUMENT OF THE COURTS ORDER RE: THE UNENFORCEABILITY OF THE 009 PATENT) - filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Exhibit 1)(Rogowski, Patricia) (Entered: 11/16/2010) SO ORDERED- re <u>349</u> Stipulation. Set POST TRIAL Briefing Schedule: (Opening Brief due 12/8/2010., Answering Brief due 12/29/2010., Reply Brief due 1/12/2010.). Signed by Judge Sue L. Robinson on 11/17/2010. (lid) (Entered: 11/17/2010)
	D574	MOTION for Leave to File Reply in Support of Plaintiff's Motion for Reargument - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 11/23/2010)
	D575	OPENING BRIEF in Support re <u>301</u> SEALED MOTION for Reconsideration Request to Modify Protective Order, <u>351</u> MOTION for Leave to File Reply in Support of Plaintiff's Motion for Reargument filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. Answering Brief/Response due date per Local Rules is 12/10/2010. (Attachments: # <u>1</u> Appendix A, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 11/23/2010)
	D576	STIPULATION TO EXTEND TIME Respond to MEMC's Motion for Reargument of the Court's Order Re: Unenforceability of the '009 Patent to December 3, 2010 - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 11/24/2010) SO ORDERED- re <u>353</u> STIPULATION TO EXTEND TIME. Set Briefing Schedule: re <u>350</u> MOTION for Reargument re <u>348</u> Judgment,. (Answering Brief due 12/3/2010.). Signed by Judge Sue L. Robinson on 11/30/2010. (lid) (Entered: 11/30/2010)

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FORM PTO-1449	SERIAL NO. 10/561,299	CASE NO. 9905/34 (BIF023273US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE December 15, 2005	GROUP ART UNIT 2891
(use several sheets if necessary)	APPLICANT(S): Jean-Pierre Joly	

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	D577	STIPULATION TO EXTEND TIME to file Motions and Opening Post-Trial Briefs to December 13, 2010 - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 12/03/2010)
	D578	REPLY BRIEF re <u>350</u> MOTION for Reargument re <u>348</u> Judgment,, (MEMCS MOTION FOR REARGUMENT OF THE COURTS ORDER RE: THE UNENFORCEABILITY OF THE 009 PATENT) Plaintiffs' Opposition to MEMC's Motion For Reargument of the Court's Order Re: The Unenforceability of the '009 Patent filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 12/03/2010) SO ORDERED- re <u>354</u> STIPULATION TO EXTEND TIME. Set Briefing Schedule: (POST TRIAL Opening Brief due 12/13/2010.). Signed by Judge Sue L. Robinson on 12/6/2010. (lid) (Entered: 12/06/2010)
	D579	EXHIBIT re <u>355</u> Reply Brief, Exhibit B to Plaintiffs' Opposition to MEMC's Motion For Reargument of the Court's Order Re: The Unenforceability of the '009 Patent by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 12/06/2010)
	D580	ANSWERING BRIEF in Opposition re <u>351</u> MOTION for Leave to File Reply in Support of Plaintiff's Motion for Reargument filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 12/20/2010. (Rogowski, Patricia) (Entered: 12/10/2010)
	D581	STIPULATION TO EXTEND TIME Stipulation and Order for Plaintiffs to file Motions and Opening Post-Trial Briefs to December 14, 2010 - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 12/13/2010)
	D582	MOTION for Judgment as a Matter of Law - MEMC'S RENEWED MOTION FOR JUDGMENT AS A MATTER OF LAW OR IN THE ALTERNATIVE FOR A NEW TRIAL - filed by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 12/13/2010)
	D583	OPENING BRIEF in Support re <u>359</u> MOTION for Judgment as a Matter of Law - MEMC'S RENEWED MOTION FOR JUDGMENT AS A MATTER OF LAW OR IN THE ALTERNATIVE FOR A NEW TRIAL filed by MEMC Electronic Materials Inc..Answering Brief/Response due date per Local Rules is 12/30/2010. (Attachments: # <u>1</u> Exhibit 1, # <u>2</u> Certificate of Service)(Rogowski, Patricia) (Entered: 12/13/2010)

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FORM PTO-1449	SERIAL NO. 10/561,299	CASE NO. 9905/34 (BIF023273US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE December 15, 2005	GROUP ART UNIT 2891
(use several sheets if necessary)	APPLICANT(S): Jean-Pierre Joly	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.	
	D584	MOTION for Judgment as a Matter of Law Plaintiffs' Renewed Motion For Judgment As A Matter of Law Or In The Alternative For A New Trial - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 12/14/2010)
	D585	OPENING BRIEF in Support re <u>361</u> MOTION for Judgment as a Matter of Law Plaintiffs' Renewed Motion For Judgment As A Matter of Law Or In The Alternative For A New Trial filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. Answering Brief/Response due date per Local Rules is 1/3/2011. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 12/14/2010)
	D586	MOTION For Injunctive Relief Plaintiffs' Motion For Injunctive Relief And To Lift Stay on Damages Discovery - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 12/14/2010)
	D587	STIPULATION TO EXTEND TIME due date for Answering and Reply Post-Trial Briefs to January 7, 2011 for Answering Brief and January 21, 2011 for Reply Brief - filed by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 12/15/2010) SO ORDERED- re <u>365</u> STIPULATION TO EXTEND TIME. Set Briefing Schedule: (Answering Post trial Brief due 1/7/2011., Reply post trial Brief due 1/21/2011.). Signed by Judge Sue L. Robinson on 12/16/2010. (lid) (Entered: 12/17/2010)
	D588	STIPULATION TO EXTEND TIME Post-Trial Answering Briefs to January 12, 2011 - filed by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 01/06/2011)
	D589	NOTICE of Appearance by Aleine Michelle Porterfield on behalf of Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc. (Attachments: # <u>1</u> Certificate of Service)(Porterfield, Aleine) (Entered: 01/07/2011)
	D590	Joint STIPULATION TO EXTEND TIME Post-trial Answering Briefs and Post-trial Reply Briefs to January 14, 2011 and January 28, 2011 - filed by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 01/12/2011)
	D591	ANSWERING BRIEF in Opposition re <u>359</u> MOTION for Judgment as a Matter of Law - MEMC'S RENEWED MOTION FOR JUDGMENT AS A MATTER OF LAW OR IN THE ALTERNATIVE FOR A NEW TRIAL filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. Reply Brief due date per Local Rules is 1/24/2011. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 01/14/2011)

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FORM PTO-1449	SERIAL NO. 10/561,299	CASE NO. 9905/34 (BIF023273US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE December 15, 2005	GROUP ART UNIT 2891
(use several sheets if necessary)	APPLICANT(S): Jean-Pierre Joly	

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	D592	ANSWERING BRIEF in Opposition re <u>361</u> MOTION for Judgment as a Matter of Law Plaintiffs' Renewed Motion For Judgment As A Matter of Law Or In The Alternative For A New Trial (MEMCS ANSWERING BRIEF IN OPPOSITION TO PLAINTIFFS RENEWED MOTION FOR JUDGMENT AS A MATTER OF LAW OR IN THE ALTERNATIVE FOR A NEW TRIAL) filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 1/24/2011. (Attachments: # <u>1</u> Certificate of Service)(Rogowski, Patricia) (Entered: 01/14/2011)
	D593	DECLARATION re <u>378</u> Answering Brief in Opposition, (DECLARATION OF ROBERT M. EVANS, JR. IN SUPPORT OF MEMCS OPPOSITION TO PLAINTIFFS RENEWED MOTION FOR JUDGMENT AS A MATTER OF LAW OR IN THE ALTERNATIVE FOR A NEW TRIAL) by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Exhibit 1, # <u>2</u> Exhibit 2, # <u>3</u> Certificate of Service)(Rogowski, Patricia) (Entered: 01/14/2011)
	D594	REDACTED VERSION of <u>376</u> Answering Brief in Opposition, to Plaintiffs' Motion for Injunctive Relief and to Lift Stay on Damages Discovery by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Certificate of Service)(Rogowski, Patricia) (Entered: 01/20/2011)
	D595	REDACTED VERSION of <u>377</u> Appendix to MEMC's Answering Brief in Opposition to Plaintiffs' Motion for Injunctive Relief and to Lift Stay on Damages Discovery by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Exhibit 1-7, # <u>2</u> Exhibit 8, # <u>3</u> Exhibit 9, # <u>4</u> Exhibit 10, # <u>5</u> Exhibit 11, # <u>6</u> Exhibit 12-13, # <u>7</u> Exhibit 14, # <u>8</u> Exhibit 15, # <u>9</u> Exhibit 16, # <u>10</u> Exhibit 17, # <u>11</u> Exhibit 18, # <u>12</u> Exhibit 19, # <u>13</u> Certificate of Service)(Rogowski, Patricia) (Entered: 01/20/2011)
	D596	Joint STIPULATION TO EXTEND TIME of Post-Trial Reply Briefs to Tuesday, February 1, 2011 - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 01/28/2011)
	D597	Joint STIPULATION TO EXTEND TIME of Post-Trial Reply Briefs to Friday, February 4, 2011 - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 01/31/2011)
	D598	REDACTED VERSION of <u>364</u> Opening Brief in Support,,, Redacted Version of Opening Brief in Support of Plaintiffs' Motion For Injunctive Relief And To Lift Stay on Damages Discovery by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Exhibit B, # <u>3</u> Exhibit C, # <u>4</u> Exhibit D, # <u>5</u> Exhibit E, # <u>6</u> Exhibit F, # <u>7</u> Exhibit G, # <u>8</u> Exhibit H, # <u>9</u> Exhibit I, # <u>10</u> Exhibit J, # <u>11</u> Exhibit K, # <u>12</u> Exhibit L, # <u>13</u> Exhibit M, # <u>14</u> Exhibit N, # <u>15</u> Exhibit O, # <u>16</u> Exhibit P, # <u>17</u> Exhibit Q, # <u>18</u> Exhibit R, # <u>19</u> Exhibit S)(Kraft, Denise) (Entered: 02/02/2011)

EXAMINER	DATE CONSIDERED
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

FORM PTO-1449	SERIAL NO. 10/561,299	CASE NO. 9905/34 (BIF023273US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE December 15, 2005	GROUP ART UNIT 2891
(use several sheets if necessary)		APPLICANT(S): Jean-Pierre Joly

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.	
	D599	REPLY BRIEF re <u>359</u> MOTION for Judgment as a Matter of Law - MEMC'S RENEWED MOTION FOR JUDGMENT AS A MATTER OF LAW OR IN THE ALTERNATIVE FOR A NEW TRIAL filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Certificate of Service)(Rogowski, Patricia) (Entered: 02/04/2011)
	D600	REPLY BRIEF re <u>361</u> MOTION for Judgment as a Matter of Law Plaintiffs' Renewed Motion For Judgment As A Matter of Law Or In The Alternative For A New Trial filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 02/04/2011)
	D601	DECLARATION re <u>387</u> Reply Brief, Declaration of Michael L. Brody in Support of Reply Brief In Support of Plaintiffs' Renewed Motion For Judgment as a Matter of Law or In The Alternative For a New Trial by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 02/04/2011)
	D602	MOTION to Strike <u>386</u> Reply Brief, Motion By Plaintiffs' To Strike Reply Brief In Support of MEMC's Renewed Motion For Judgment as a Matter of Law or, In The Alternative, a New Trial (D.I. 386) - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 02/08/2011)
	D603	OPENING BRIEF in Support re <u>390</u> MOTION to Strike <u>386</u> Reply Brief, Motion By Plaintiffs' To Strike Reply Brief In Support of MEMC's Renewed Motion For Judgment as a Matter of Law or, In The Alternative, a New Trial (D.I. 386) MOTION to Strike <u>386</u> Reply Brief, Motion By Plaintiffs' To Strike Reply Brief In Support of MEMC's Renewed Motion For Judgment as a Matter of Law or, In The Alternative, a New Trial (D.I. 386) filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. Answering Brief/Response due date per Local Rules is 2/25/2011. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 02/08/2011)
	D604	DECLARATION re <u>391</u> Opening Brief in Support,, Declaration of Marcus T. Hall in Support of Plaintiffs' Opening Brief in Support of Motion to Strike Reply Brief In Support of MEMC's Renewed Motion For Judgment as a Matter of Law or, In The Alternative, a New Trial (D.I. 386) by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 02/08/2011)
	D605	REDACTED VERSION of <u>389</u> Reply Brief, Redacted Version of Reply Brief in Support of Plaintiffs' Motion For Injunctive Relief And To Lift Stay on Damages Discovery by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 02/09/2011)

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FORM PTO-1449	SERIAL NO. 10/561,299	CASE NO. 9905/34 (BIF023273US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE December 15, 2005	GROUP ART UNIT 2891
(use several sheets if necessary)	APPLICANT(S): Jean-Pierre Joly	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.	
	D606	ANSWERING BRIEF in Opposition re <u>390</u> MOTION to Strike <u>386</u> Reply Brief, Motion By Plaintiffs' To Strike Reply Brief In Support of MEMC's Renewed Motion For Judgment as a Matter of Law or, In The Alternative, a New Trial (D.I. 386) MOTION to Strike <u>386</u> Reply Brief, Motion By Plaintiffs' To Strike Reply Brief In Support of MEMC's Renewed Motion For Judgment as a Matter of Law or, In The Alternative, a New Trial (D.I. 386) filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 2/28/2011. (Attachments: # <u>1</u> Exhibit 1-3, # <u>2</u> Certificate of Service)(Rogowski, Patricia) (Entered: 02/18/2011)
	D607	REPLY BRIEF re <u>390</u> MOTION to Strike <u>386</u> Reply Brief, Motion By Plaintiffs' To Strike Reply Brief In Support of MEMC's Renewed Motion For Judgment as a Matter of Law or, In The Alternative, a New Trial (D.I. 386) MOTION to Strike <u>386</u> Reply Brief, Motion By Plaintiffs' To Strike Reply Brief In Support of MEMC's Renewed Motion For Judgment as a Matter of Law or, In The Alternative, a New Trial (D.I. 386) filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 02/28/2011)

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